# NSN 5962-01-307-9936

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# **Overall Height:**

Between 0.357 inches and 0.432 inches

## **Body Length:**

1.490 inches

# Body Width:

Between 0.500 inches and 0.610 inches

### **Body Height:**

Between 0.172 inches and 0.217 inches

### **Maximum Power Dissipation Rating:**

1.0 watts

### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Electrostatic sensitive and hermetically sealed and burn in and programmable and ultraviolet erasable

#### Inclosure Material:

Ceramic

### Inclosure Configuration:

Dual-in-line

# Output Logic Form:

N-type metal oxide-semiconductor logic

#### **Input Circuit Pattern:**

16 input

### **Case Outline Source And Designator:**

D-10 mil-m-38510

### **Terminal Surface Treatment:**

Solder

### Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 7.0 volts power source

### **Time Rating Per Chacteristic:**

200.00 nanoseconds propagation delay time, low to high level output and 200.00 nanoseconds propagation delay time, high to low level

output

### Memory Device Type:

Rom

### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

### **Terminal Type And Quantity:**

28 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

Fiig:

A458a0

